



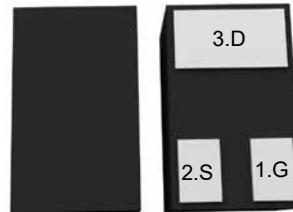
# PJM01N20KDC

## N-Channel Enhancement Mode Power MOSFET

### Features

- Low gate charge and  $R_{DS(ON)}$
- ESD protected(HBM) up to 2KV
- $V_{DS} = 20V, I_D = 0.8A$
- $R_{DS(on)} < 310m\Omega @ V_{GS} = 4.5V$

DFN1x0.6-3L



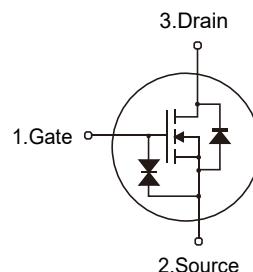
1. Gate 2. Source 3. Drain

### Applications

- Load switch and in PWM applications
- Power management

Marking Code: JN

Schematic Diagram



### Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Drain Current-Continuous	$I_D$	0.8	A
Drain Current-Pulsed <sup>Note1</sup>	$I_{DM}$	3.2	A
Maximum Power Dissipation	$P_D$	0.35	W
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C

### Thermal Characteristics

Thermal Resistance, Junction-to-Ambient <sup>Note2</sup>	$R_{\theta JA}$	357	°C/W
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### Electrical Characteristics

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	20	--	--	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	--	--	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	--	--	±10	μA
Gate Threshold Voltage <sup>Note3</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.35	0.75	1.1	V
Drain-Source On-Resistance <sup>Note3</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =0.6A	--	180	300	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =0.5A	--	260	350	mΩ
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =0.2A	--	415	700	mΩ
Forward Transconductance <sup>Note3</sup>	g <sub>FS</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =0.5A	--	2	--	S
<b>Dynamic Characteristics</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz	--	56	--	pF
Output Capacitance	C <sub>oss</sub>		--	20	--	pF
Reverse Transfer Capacitance	C <sub>rss</sub>		--	2.5	--	pF
<b>Switching Characteristics</b>						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =10V, I <sub>D</sub> =0.5A V <sub>GS</sub> =4.5V, R <sub>G</sub> =10Ω	--	2	--	nS
Turn-on Rise Time	t <sub>r</sub>		--	18.8	--	nS
Turn-off Delay Time	t <sub>d(off)</sub>		--	10	--	nS
Turn-off Fall Time	t <sub>f</sub>		--	23	--	nS
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =0.5A, V <sub>GS</sub> =4.5V	--	1	--	nC
Gate-Source Charge	Q <sub>gs</sub>		--	0.28	--	nC
Gate-Drain Charge	Q <sub>gd</sub>		--	0.22	--	nC
<b>Source-Drain Diode Characteristics</b>						
Diode Forward Voltage <sup>Note3</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>s</sub> =0.8A	--	--	1.2	V
Diode Forward Current <sup>Note2</sup>	I <sub>s</sub>		--	--	0.8	A

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

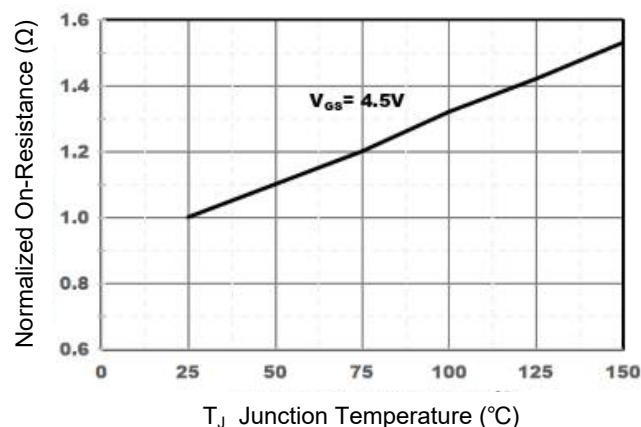
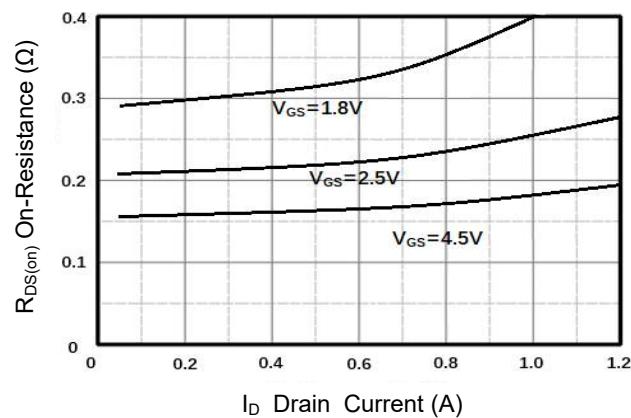
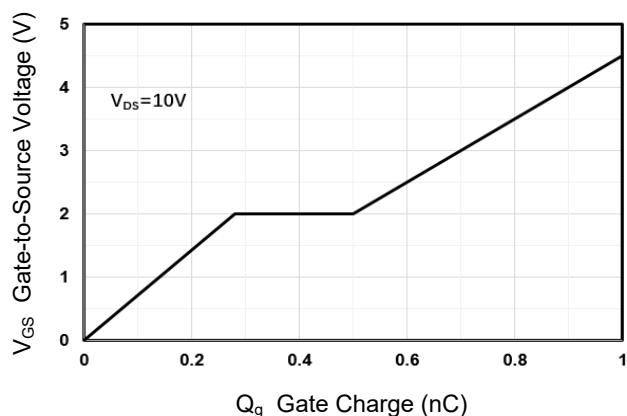
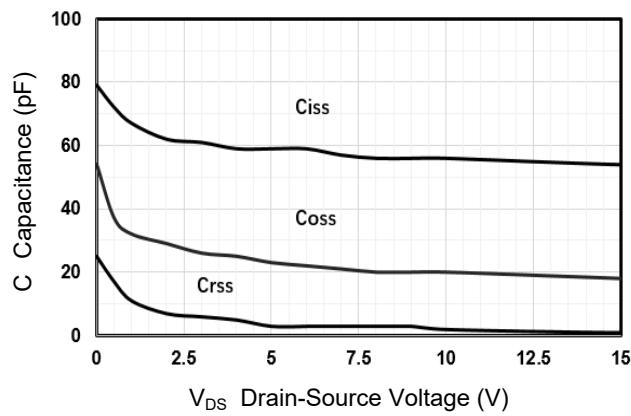
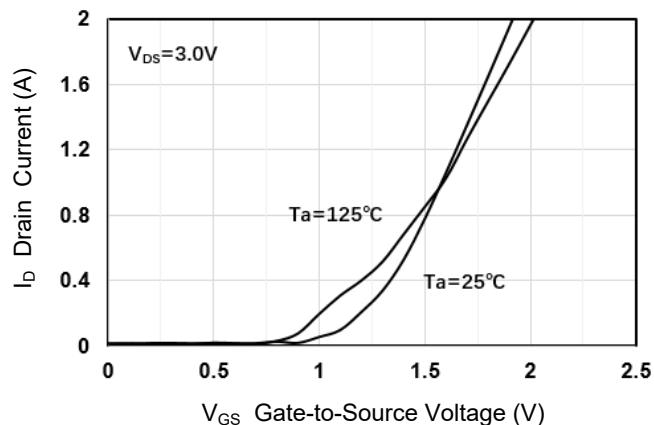
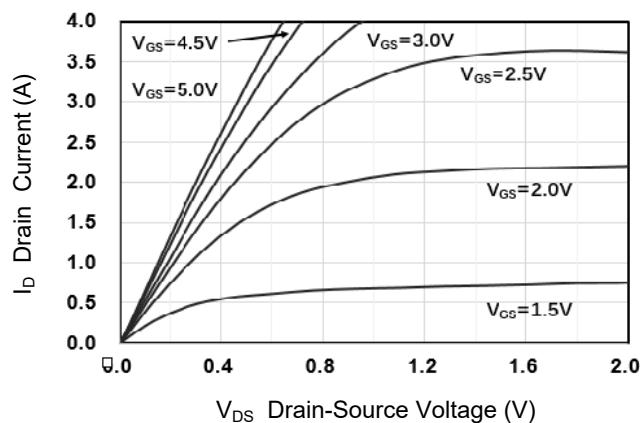
3. Pulse Test: Pulse width≤300μs, duty cycle≤0.5%.



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## N-Channel Enhancement Mode Power MOSFET

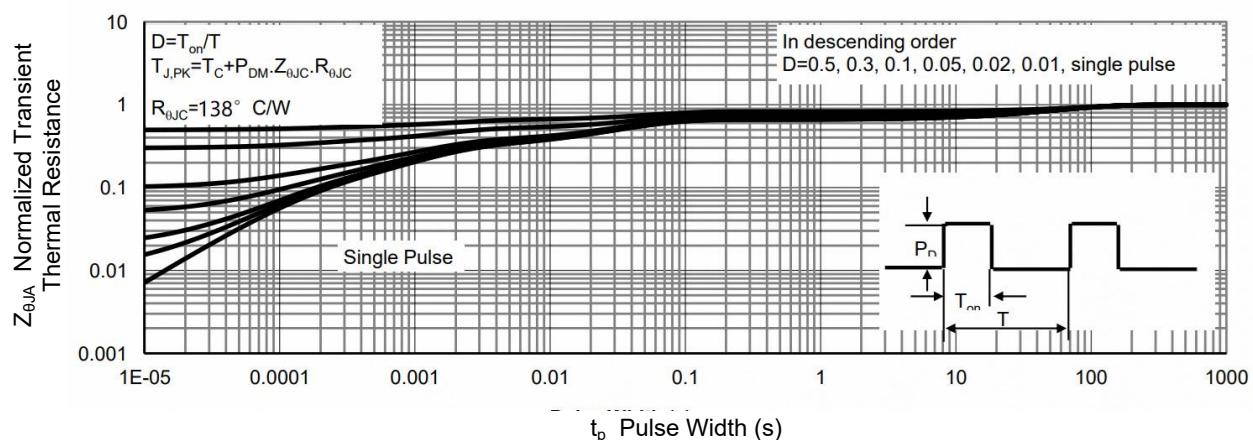
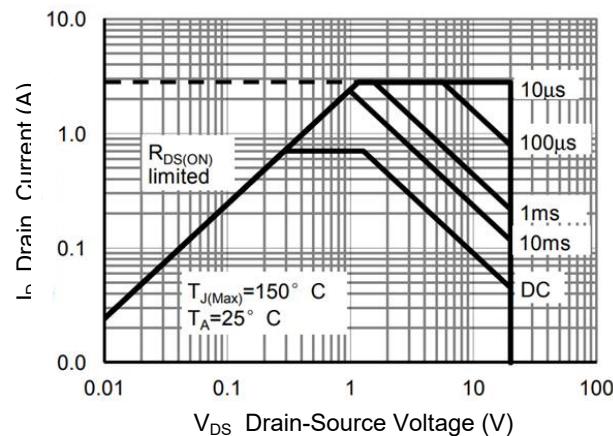
### Typical Characteristic Curves





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## N-Channel Enhancement Mode Power MOSFET





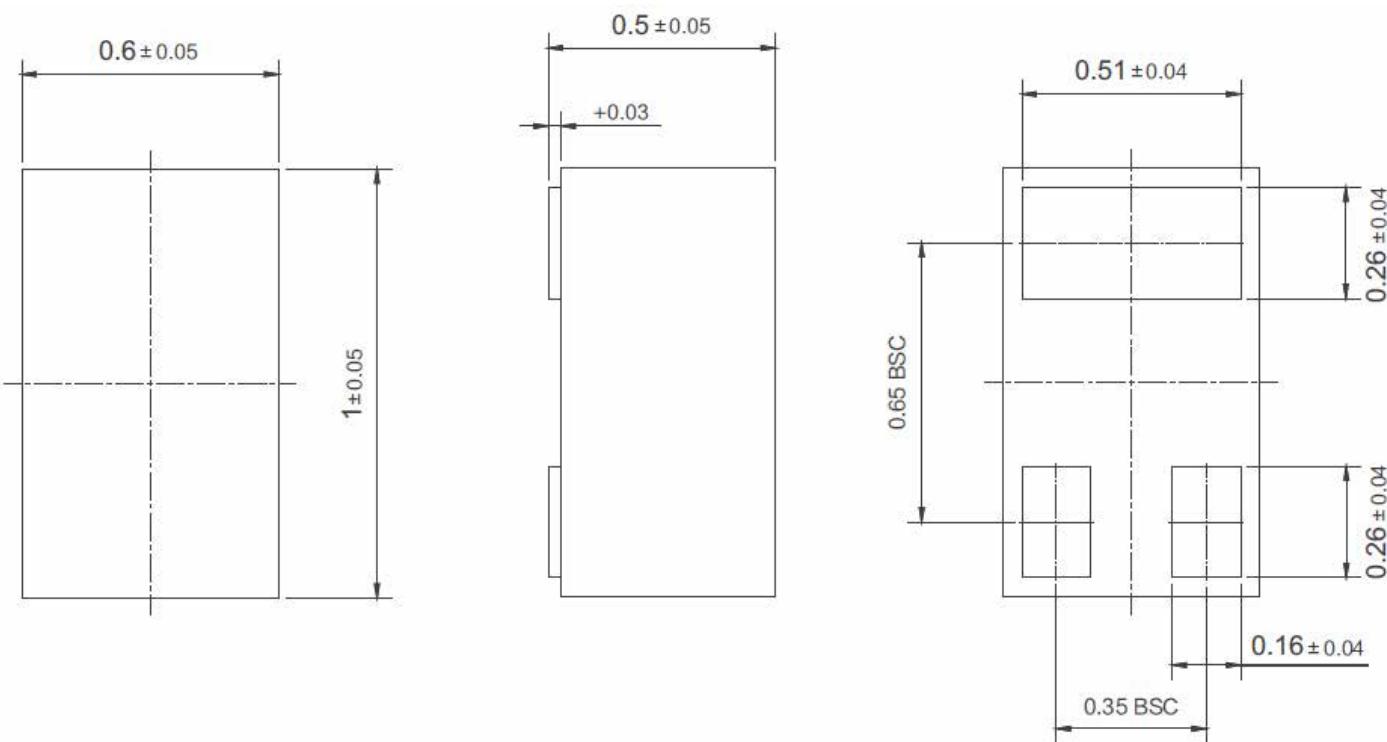
# PJM01N20KDC

## N-Channel Enhancement Mode Power MOSFET

### Package Outline

DFN1x0.6-3L-0009

Dimensions in mm



### Ordering Information

Device	Package	Shipping
PJM01N20KDC	DFN1x0.6-3L	10,000PCS/Reel&7inches

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